Infrared Light Emitting Diode OP205CL



Features:

- High power GaAlAs
- Narrow beam angle—near parallel beam
- 875 nm wavelength
- TO-46 package
- · Wide operating temperature range



Description:

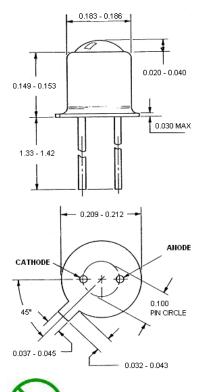
The **OP205CL** is a high efficiency GaAlAs infrared LED mounted in a TO-46 metal can package. The device features a special dome lens that allows a very narrow beam angle. The result is a near parallel beam that is useful in applications that requires a collimated light source with a uniform intensity pattern.

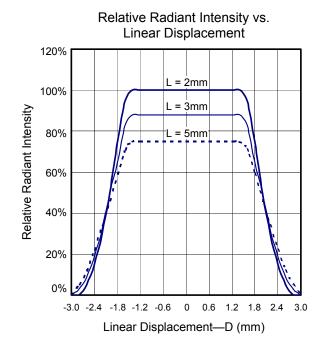
OP205CL LED is mechanically and spectrally matched to OP800 series phototransistors.

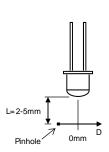
Applications:

- · Optical encoders
- · Triangulation sensors
- Long distance sensing

	Ordering In	formation	
Part Number	LED Peak Wavelength	Total Beam Angle	Lead Length
OP205CL	875 nm	10°	34mm









RoHS

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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Absolute Maximum Ratings T_A = 25° C unless otherwise noted

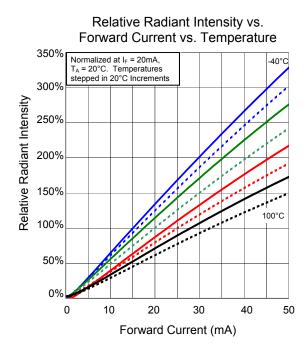
Storage Temperature Range	-40° C to +125° C
Operating Temperature Range	-40° C to +100° C
Lead Soldering Temperature	260° C ⁽¹⁾
Reverse Voltage	3.0 V
Continuous Forward Current	50 mA
Power Dissipation	160 mW ⁽²⁾

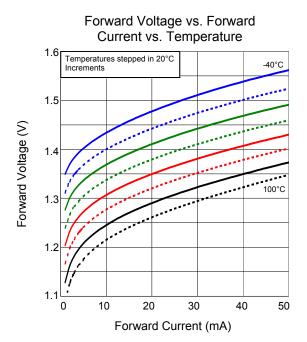
Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
Po	Radiant Intensity	8.5	12.0	1	mW	I _F = 50mA ⁽³⁾
V _F	Forward Voltage	-	-	2.0	V	I _F = 50mA
I _R	Reverse Current	-	ı	10	μΑ	V _R = 3.0V
λ_{P}	Peak Emission Wavelength	-	875	-	nm	I _F = 20mA
Θ_{HP}	Total Emission Angle at Half Power Points	-	6	10	Deg.	I _F = 20mA

Notes:

- Solder time less than 5 seconds at temperature extreme.
- 2. De-rate linearly at 2.17 mW/° C above 25° C.
- 3. Total Optical Power (P_O) is measured by OPTEK Technology equipment.





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